RENESAS

μ**PD5902T7K**

CMOS Integrated Circuits High Power SPDT Switch

R09DS0046EJ0200 Rev.2.00 Nov 19, 2012

Data Sheet

DESCRIPTION

The μ PD5902T7K is a CMOS MMIC SPDT (Single Pole Double Throw) switch for GSM and UMTS/LTE main Antenna switching and other High Power RF switching applications up to +35 dBm.

This device can operate frequency from 0.05 to 6.0 GHz, having low insertion loss and high isolation.

This device is housed in a 12-pin plastic QFN (Quad Flat Non-Leaded) (T7K) package.

FEATURES

- Low control voltage : $V_{cont} = 1.3 \text{ V MIN.}, V_{DD} = 2.3 \text{ V MIN.}$
 - Low insertion loss : $L_{ins} = 0.35/0.40 \text{ dB TYP}$. @ f = 1.0/2.0 GHz
- High isolation : ISL = 45/37 dB TYP. @ f = 1.0/2.0 GHz
- High Handling power : $P_{in (0.1dB)} = +38 \text{ dBm TYP}$. @f = 0.9/2.0 GHz
- High-density surface mounting : 12-pin plastic QFN (T7K) package $(2.0 \times 2.0 \times 0.6 \text{ mm})$
- No DC blocking capacitors required.

APPLICATIONS

- GSM and UMTS/LTE main Antenna switching etc.
- Other RF switching Applications.
- Antenna tuning Applications.

ORDERING INFORMATION

Part Number	Order Number	Package	Marking		Supplying Form
μPD5902T7K-E2	μPD5902T7K-E2-A	12-pin plastic QFN (T7K) (Pb-Free)	5902	•	Embossed tape 8 mm wide Pin 10, 11 and 12 face the perforation side of the tape Qty 3 kpcs/reel

Remark To order evaluation samples, please contact your nearby sales office. Part number for sample order: μ PD5902T7K-A

CAUTION

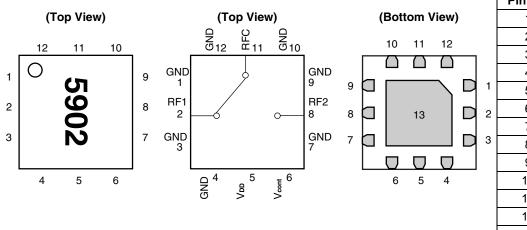
Although this device is designed to be as robust as possible, ESD (Electrostatic Discharge) can damage this device. This device must be protected at all times from ESD. Static charges may easily produce potentials of several kilovolts on the human body or equipment, which can discharge without detection. Industry-standard ESD precautions must be employed at all times.

The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.



<R> PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



	Pin No.	Pin Name
	1	GND
	2	RF1
	3	GND
	4	GND
1	5	V _{DD}
2	6	V _{cont}
	7	GND
3	8	RF2
	9	GND
	10	GND
	11	RFC
	12	GND
	13	GND

SW TRUTH TABLE

V _{cont}	RFC-RF1	RFC-RF2
High	ON	OFF
Low	OFF	ON

ABSOLUTE MAXIMUM RATINGS ($T_A = +25^{\circ}C$, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Supply Voltage	V _{DD}	3.6	V
Control Voltage	V _{cont}	3.6	V
Input Power	Pin	+38	dBm
Operating Ambient Temperature	T _A	-40 to +85	°C
Storage Temperature	T _{stg}	–55 to +125	°C

RECOMMENDED OPERATING RANGE (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Operating Frequency	f	0.05	-	6.0	GHz
Supply Voltage	V _{DD}	2.3	-	3.3	V
Control Voltage (High)	V _{cont (H)} Note	1.3	-	V _{DD}	V
Control Voltage (Low)	V _{cont (L)}	0	-	0.4	V

Note: $V_{cont} \leq V_{DD}$

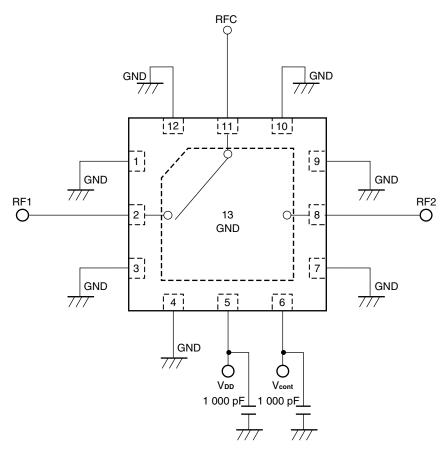


ELECTRICAL CHARACTERISTICS (T_A = +25°C, V_{DD} = 2.5 V, V_{cont (H)} = 1.8 V, V_{cont (L)} = 0 V, Z₀ = 50 Ω , unless otherwise specified)

	Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
ĺ	Insertion Loss	L _{ins} 1	$f = 0.05$ to 0.5 GHz, $P_{in} = 0$ dBm	-	0.30	0.45	
	L _{ins} 2	f = 0.5 to 1.0 GHz	_	0.35	0.50		
		L _{ins} 3	f = 1.0 to 2.0 GHz	_	0.40	0.55	
		L _{ins} 4	f = 2.0 to 2.7 GHz	-	0.45	0.75	
		L _{ins} 5	f = 2.7 to 3.8 GHz	-	0.50	0.80	
		L _{ins} 6	f = 3.8 to 6.0 GHz	-	0.60	0.95	
Ì	Isolation	ISL1	$f = 0.05$ to 0.5 GHz, $P_{in} = 0$ dBm	45	50	-	
	(RFC – RF1,2)	ISL2	f = 0.5 to 1.0 GHz	40	45	-	
		ISL3	f = 1.0 to 2.0 GHz	32	37	_	dB
		ISL4	f = 2.0 to 2.7 GHz	30	35	-	
		ISL5	f = 2.7 to 3.8 GHz	25	30	_	
		ISL6	f = 3.8 to 6.0 GHz	_	23	_	
ľ	Return Loss	RL1	f = 0.05 to 3.8 GHz	15	18	_	
	(RFC)	RL2	f = 3.8 to 6.0 GHz	_	15	_	-
Ì	Return Loss	RL1	f = 0.05 to 3.8 GHz	15	18	_	
	(RF1,2)	RL2	f = 3.8 to 6.0 GHz	_	15	_	
	0.1 dB Loss Compression Input Power	P _{in(0.1dB)} 1	f = 0.9 GHz	+36.0	+38.0 Note	_	
		P _{in(0.1dB)} 2	f = 2.0 GHz	+36.0	+38.0 Note	_	dBm
ľ	Harmonics	2f0	f = 0.9 GHz, P _{in} = +35 dBm	75	80	_	
		3f0	-	70	75	_	
		2f0	f = 2.0 GHz, P _{in} = +33 dBm	75	85	_	dBc
		3f0		70	80	_	
	2nd Order Inter Modulation		$f = 835 \text{ MHz}, P_{in} = +20 \text{ dBm}$ $f = 45 \text{ MHz}, P_{in} = -15 \text{ dBm}$	_	-98	-93	
	Distortion	IMD2	f = 1 950 MHz, P _{in} = +20 dBm f = 190MHz, P _{in} = -15 dBm	_	-105	-100	dBm
	3rd Order Inter Modulation Distortion IMD3	IMD3	f = 835 MHz, P _{in} = +20 dBm f = 790 MHz, P _{in} = -15 dBm	_	-110	-105	abiii
			f = 1 950 MHz, P _{in} = +20 dBm f = 1 760 MHz, P _{in} = -15 dBm	-	-110	-105	
	Input 3rd order Intercept Point	IIP ₃	f = 2 500 MHz, P _{in} = +20 dBm f = 2 501 MHz, P _{in} = +20 dBm	65	70	_	dBm
Ī	Switch Control Speed	T_{sw}	50% CTL to 90/10%	-	2.0	5.0	µsec
	Supply Current	I _{DD}	Active Mode No RF	-	130	250	
	Control Current	I _{cont} (H)	V _{cont} : High No RF	-	-	1	μA
			V _{cont} : Low No RF	1			1

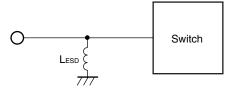
Note: Absolute Maximum Ratings

<R> EVALUATION CIRCUIT



The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

APPLICATION INFORMATION

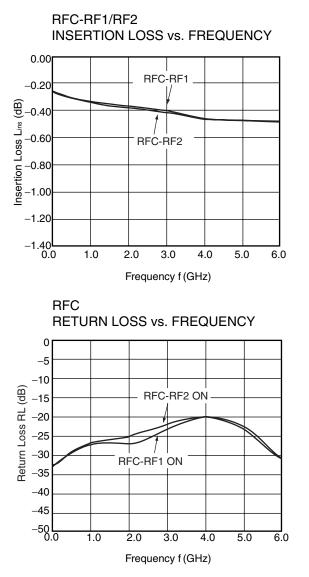


• L_{ESD} provides a means to increase the ESD protection on a specific RF port, typically the port attached to the antenna.

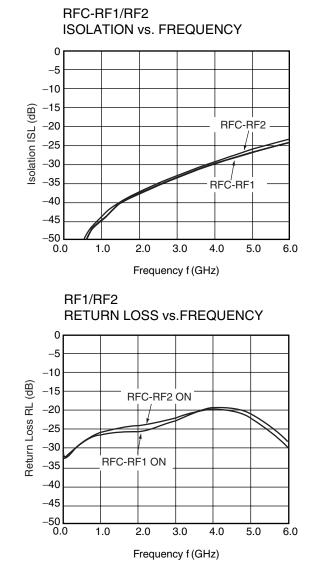


TYPICAL CHARACTERISTICS

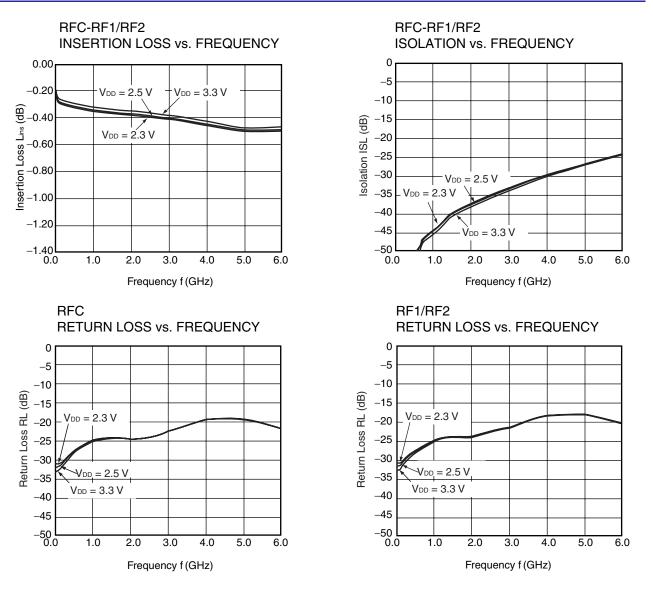
(T_A = +25°C, V_{DD} = 2.5 V, V_{cont (H)} = 1.8 V, V_{cont (L)} = 0 V, Z₀ = 50 Ω , unless otherwise specified)



Remark The graphs indicate nominal characteristics.

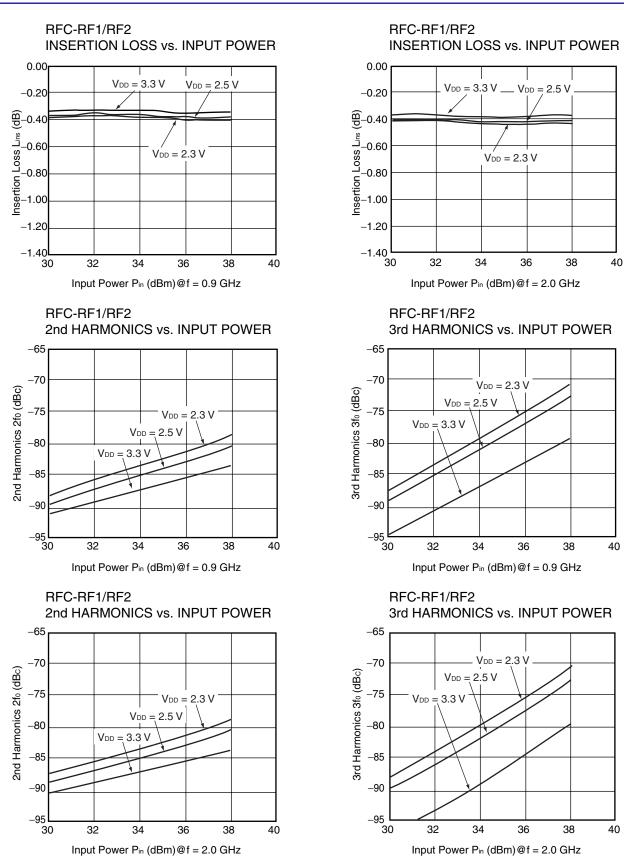






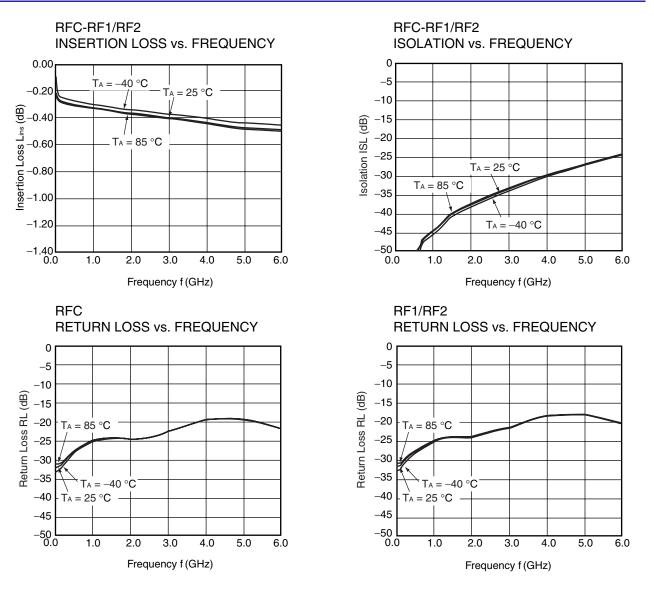
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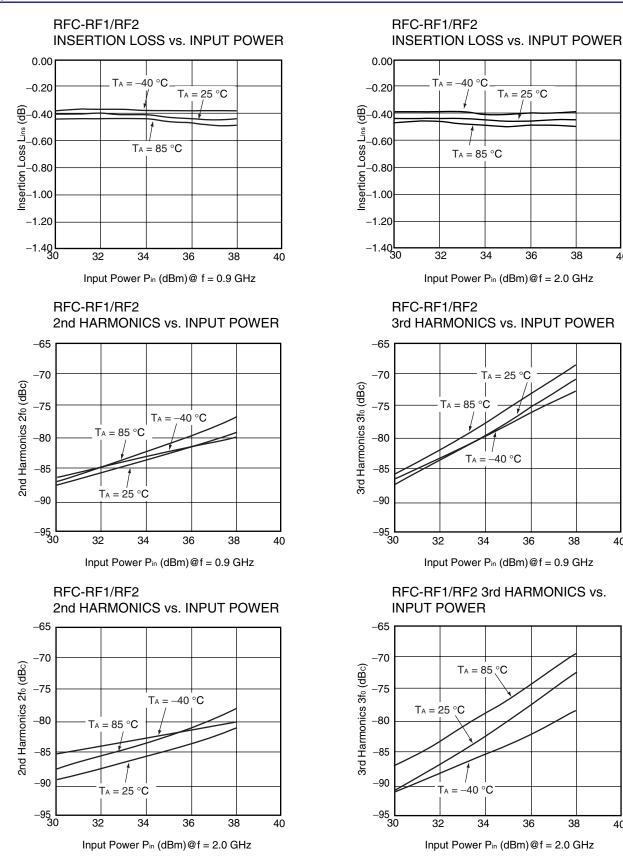
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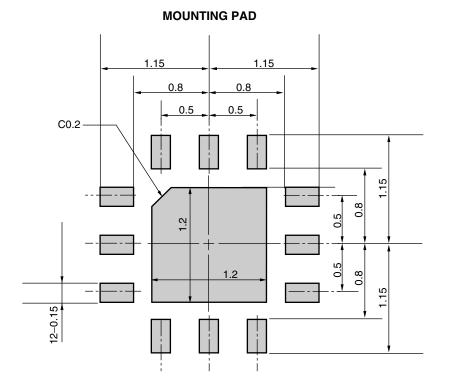
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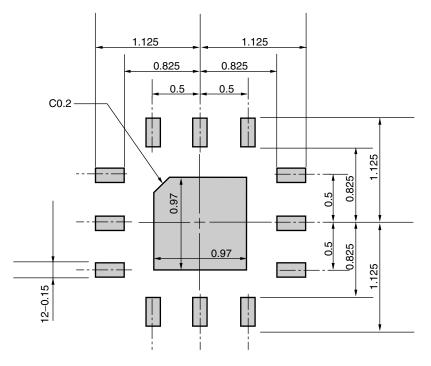
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MOUNTING PAD LAYOUT DIMENSIONS

12-PIN PLASTIC QFN (T7K) (UNIT: mm)



SOLDER MASK



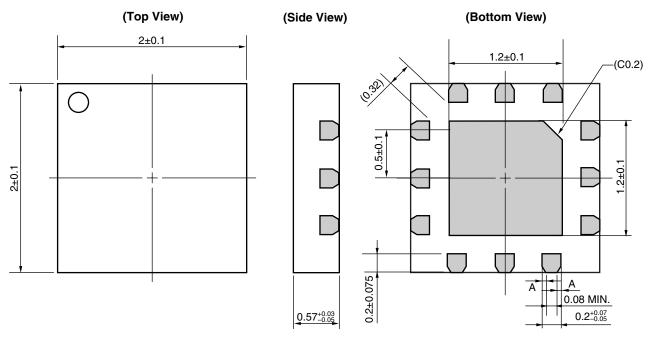
Solder thickness : 0.1 mm

Remark The mounting pad layout in this document is for reference only.When designing PCB, please consider workability of mounting, solder joint reliability, prevention of solder bridge and so on, in order to optimize the design.



PACKAGE DIMENSIONS

12-PIN PLASTIC QFN (T7K) (UNIT: mm)



Remark A > 0

(): Reference value



RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol	
Infrared Reflow	Peak temperature (package surface temperature)	: 260°C or below	IR260
	Time at peak temperature	: 10 seconds or less	
	Time at temperature of 220°C or higher	: 60 seconds or less	
	Preheating time at 120 to 180°C	: 120±30 seconds	
	Maximum number of reflow processes	: 3 times	
	Maximum chlorine content of rosin flux (% mass)	: 0.2% (Wt.) or below	
Partial Heating	Peak temperature (terminal temperature)	: 350°C or below	HS350
	Soldering time (per side of device)	: 3 seconds or less	
	Maximum chlorine content of rosin flux (% mass)	: 0.2% (Wt.) or below	

CAUTION

Do not use different soldering methods together (except for partial heating).



Revision History

μ PD5902T7K Data Sheet

		Description		
Rev.	Date	Page	Summary	
1.00	Sep 10, 2012	-	First edition issued	
2.00	Nov 19, 2012	p.2	p.2 The block diagram is changed.	
		p.3	The symbol indicating the range between terminals is changed from "to" to "-".	
		p.4	The evaluation circuit is changed.	

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